

INFORMATION DISCLOSURE CITATION

ATTY. DOCKET NO.

124-601

APPLICANT

CANHAM et al.

FILING DATE

September 17, 1997

SERIAL NO

10/051,059
~~08/913,414~~

~~08/913,414~~

JC821 U.S. PTO

10/p51059

01/22/02

(Use several sheets if necessary)

GROUP

~~2811~~ 2826

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

							TRANSLATION	
	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	YES	NO	
MLT	2 268 333	1/1994	GB	<u> </u>	<u> </u>			
			/					

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

MLT	Canham, "Silicon Quantum Wire Array Fabrication by Electrochemical and Chemical Dissolution of Wafers" <i>Appl. Phys. Lett.</i> 57 (10), Sept. 1990, pages 1046-1048
	Badoz et al, "Physical Characterization of Silicon and Porous Silicon Based Electroluminescent Diodes" pages 569-473D, 1993.
	Pulsford et al, "Carrier Injection and Transport in Porous Silicon Schottky Diodes" <i>Journal of Luminescence</i> 57 (1993) 181-184
	Amisola et al, "Scanning Probe Microscopy and Scanning Tunneling Spectroscopy of Porous Silicon" <i>Appl. Phys. Lett.</i> 61 (21), Nov. 1992, pages 2595-2597
	Canham et al "Characterization of Microporous Si by Flow Calorimetry: Comparison with a Hydrophobic SiO ₂ Molecular Sieve" <i>J. Appl. Phys.</i> 72 (4), Aug. 1992, pages 1558-1565
	S. Sze, "Physics of Semiconductor Devices", 1981.
	Van Buuren et al, "Photoelectron Spectroscopy Measurements of the Band Gap in Porous Silicon" <i>Appl. Phys. Lett.</i> 63 (21) Nov. 1993
	D.A.G. Bruggeman, <i>Ann. Phys.</i> , Vol. 24, pages 636-664, 1935
MLT	Delerue et al, "Theoretical Descriptions of Porous Silicon" <i>Thin Solid Films</i> 255 (1995) 27-34
*Examiner	Minhloan Tran
	Date Considered
	2/2003

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

Form PTO-FB-A820 (Also PTO-1449)

